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<u>Vishay Semiconductor/Diodes Division</u> <u>SM8A27HE3/2D</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Datasheet of SM8A27HE3/2D - TVS DIODE 22VWM 40VC DO218AB

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VISHAY www.vishay.com

Surface Mount PAR® Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



DO-218AB

27 V

6600 W

8 W

22 V

130 A 700 A

175 °C

Uni-directional

DO-218AB

PRIMARY CHARACTERISTICS

 V_{BR}

P_{PPM} (10 x 1000 μs)

 P_D

 V_{WM}

 I_{RSM}

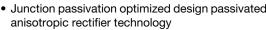
 I_{FSM}

 T_J max.

Polarity

Package

F	EATURES
•	Junction pas





• T_J = 175 °C capability suitable for high reliability and automotive requirement

RoHS COMPLIANT

- · Low leakage current
- Low forward voltage drop
- · High surge capability
- Meets ISO7637-2 surge specification
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

TVPI	CAL	APPL	ICAT	IONS
		AFFL	IVAI	10113

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting. especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AB

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Heatsink is anode

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VALUE	UNIT	
Peak pulse power dissipation with 10/1000 µs waveform	P _{PPM}	6600	W	
Power dissipation on infinite heatsink at T _C = 25 °C (fig. 1)	P _D	8.0	W	
Non-repetitive peak reverse surge current for 10 µs/10 ms exponentially decaying waveform	I _{RSM}	130	А	
Maximum working stand-off voltage	V _{WM}	22.0	V	
Peak forward surge current 8.3 ms single half sine-wave	I _{FSM}	700	Α	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175	°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
DEVICE TYPE	BREAKDOWN VOLTAGE V _{BR} AT I _T (V)		TEST CURRENT I _T (mA)	STAND-OFF VOLTAGE	
	MIN.	MAX.	(IIIA)	(V)	
SM8A27	24	30	10	22	

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ADDITIONAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Zener voltage temperature coefficient	$I_Z = 10 \text{ mA}$	V_{ZTC}	-	-	36	mV/°C	
Clamping voltage for 10 µs/10 ms exponentially decaying waveform	I _{PP} = 75 A	V _C	-	-	40.0	V	
Instantaneous forward voltage	$I_F = 6.0 \text{ A}$	V _F ⁽¹⁾	-	-	0.98	V	
instantaneous forward voltage	I _F = 100 A		-	0.93	-	·	
Reverse leakage current	Rated V_{WM} $T_J = 25 ^{\circ}\text{C}$ $T_J = 175 ^{\circ}\text{C}$	- I _R	-	-	1.0	- μΑ	
neverse leakage current			-	-	50.0		

Note

⁽¹⁾ Measured on a 300 µs square pulse width

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER SYMBOL VALUE UNIT					
Typical thermal resistance, junction to case	$R_{\theta JC}$	0.90	°C/W		

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SM8A27HE3/2D ⁽¹⁾	2.605	2D	750	13" diameter plastic tape and reel, anode towards the sprocket hole	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

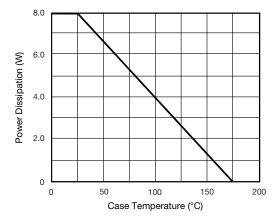


Fig. 1 - Power Derating Curve

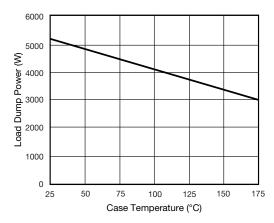


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)

⁽¹⁾ AEC-Q101 qualified



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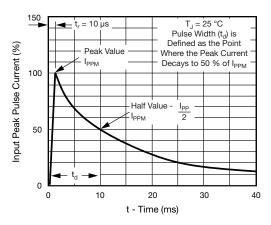


Fig. 3 - Pulse Waveform

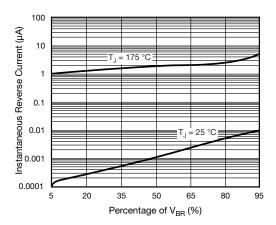


Fig. 6 - Typical Reverse Characteristics

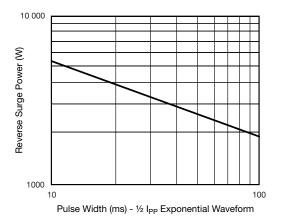


Fig. 4 - Reverse Power Capability

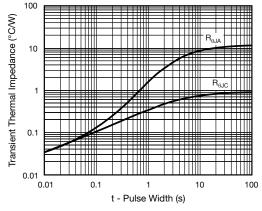


Fig. 7 - Typical Transient Thermal Impedance

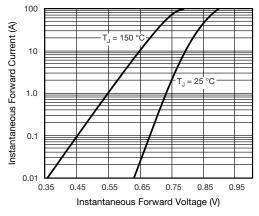


Fig. 5 - Typical Instantaneous Forward Characteristics



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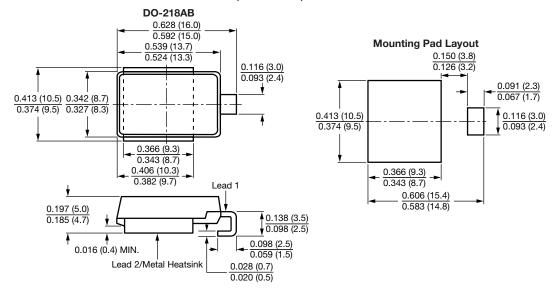


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of SM8A27HE3/2D - TVS DIODE 22VWM 40VC DO218AB

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